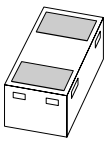


BAP55L

Silicon PIN diode

Rev. 01 — 5 April 2005 Preliminary data sheet

1. Product profile

1.1 General description

Planar PIN diode in a SOD882 leadless ultra small plastic SMD package.

1.2 Features

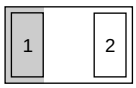
- High speed switching for RF signals
- Low diode capacitance
- Low forward resistance
- Very low series inductance
- For applications up to 3 GHz

1.3 Applications

- RF attenuators and switches

2. Pinning information

Table 1: Discrete pinning

Pin	Description	Simplified outline	Symbol
1	cathode [1]	 Transparent top view	 sym006
2	anode		

[1] The marking bar indicates the cathode.

3. Ordering information

Table 2: Ordering information

Type number	Package		
	Name	Description	Version
BAP55L	-	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.5$ mm	SOD882

PHILIPS

4. Marking

Table 3: Marking

Type number	Marking code
BAP55L	E6

5. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	50	V
I_F	forward current		-	100	mA
P_{tot}	total power dissipation	T_s = 90 °C	-	500	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–65	+150	°C

6. Thermal characteristics

Table 5: Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-sp)}$	thermal resistance from junction to soldering point		100	K/W

7. Characteristics

Table 6: Characteristics

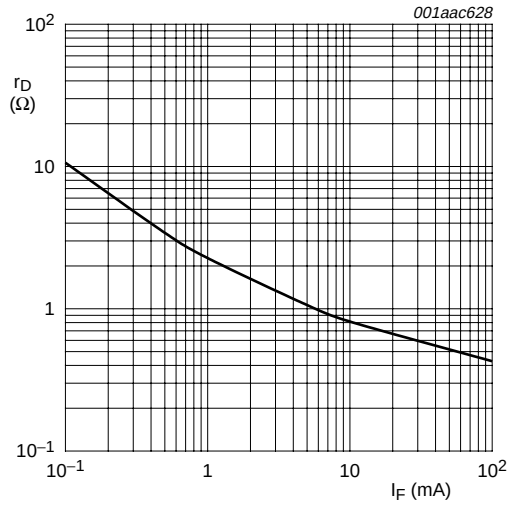
T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_F	forward voltage	I_F = 50 mA	-	0.95	1.1	V
I_R	reverse current	V_R = 20 V	-	-	10	nA
		V_R = 50 V	-	-	0.1	µA
C_d	diode capacitance	f = 1 MHz; Figure 2				
		V_R = 0 V	-	0.27	-	pF
		V_R = 1 V	-	0.23	-	pF
		V_R = 20 V	-	0.18	0.28	pF
r_D	diode forward resistance	f = 100 MHz; Figure 1				
		I_F = 0.5 mA	-	3.4	4.5	Ω
		I_F = 1 mA	-	2.3	3.3	Ω
		I_F = 10 mA	-	0.8	1.2	Ω
		I_F = 100 mA	-	0.4	0.7	Ω

Table 6: Characteristics *...continued*

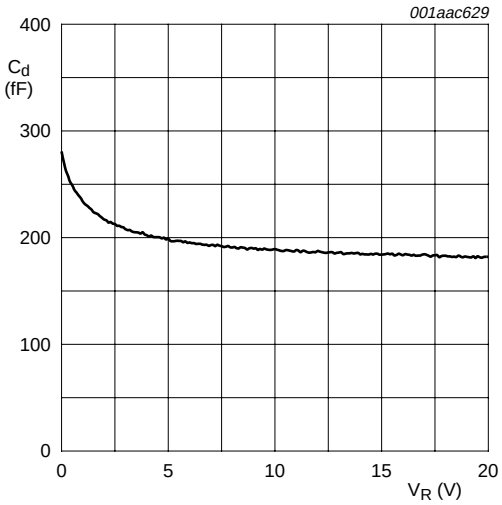
T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\|s_{12}\|^2$	isolation	V_R = 0 V; Figure 4				
		f = 900 MHz	-	17.6	-	dB
		f = 1800 MHz	-	13	-	dB
		f = 2450 MHz	-	11.1	-	dB
$\|s_{21}\|^2$	insertion loss	I_F = 0.5 mA; Figure 3				
		f = 900 MHz	-	0.25	-	dB
		f = 1800 MHz	-	0.27	-	dB
		f = 2450 MHz	-	0.29	-	dB
		I_F = 1 mA; Figure 3				
		f = 900 MHz	-	0.17	-	dB
		f = 1800 MHz	-	0.19	-	dB
		f = 2450 MHz	-	0.21	-	dB
		I_F = 10 mA; Figure 3				
		f = 900 MHz	-	0.07	-	dB
		f = 1800 MHz	-	0.09	-	dB
		f = 2450 MHz	-	0.12	-	dB
		I_F = 100 mA; Figure 3				
		f = 900 MHz	-	0.05	-	dB
		f = 1800 MHz	-	0.07	-	dB
		f = 2450 MHz	-	0.09	-	dB
τ_L	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω; measured at I_R = 3 mA	-	0.28	-	µs
L_S	series inductance		-	0.6	-	nH



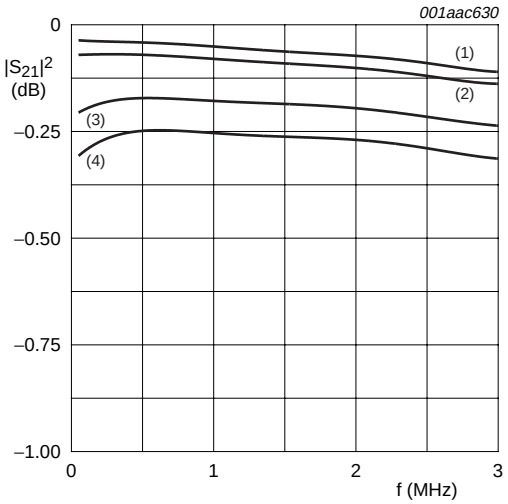
f = 100 MHz; T_j = 25 °C.

Fig 1. Forward resistance as a function of forward current; typical values



f = 1 MHz; T_j = 25 °C.

Fig 2. Diode capacitance as a function of reverse voltage; typical values



(1) I_F = 100 mA.

(2) I_F = 10 mA.

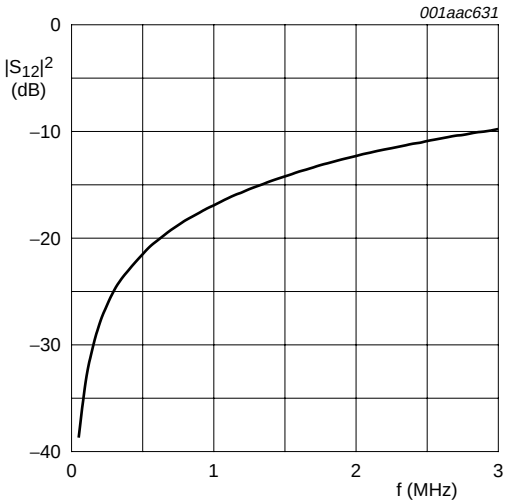
(3) I_F = 1 mA.

(4) I_F = 0.5 mA.

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network.

T_{amb} = 25 °C.

Fig 3. Insertion loss ($|s_{21}|^2$) of the diode as a function of frequency; typical values



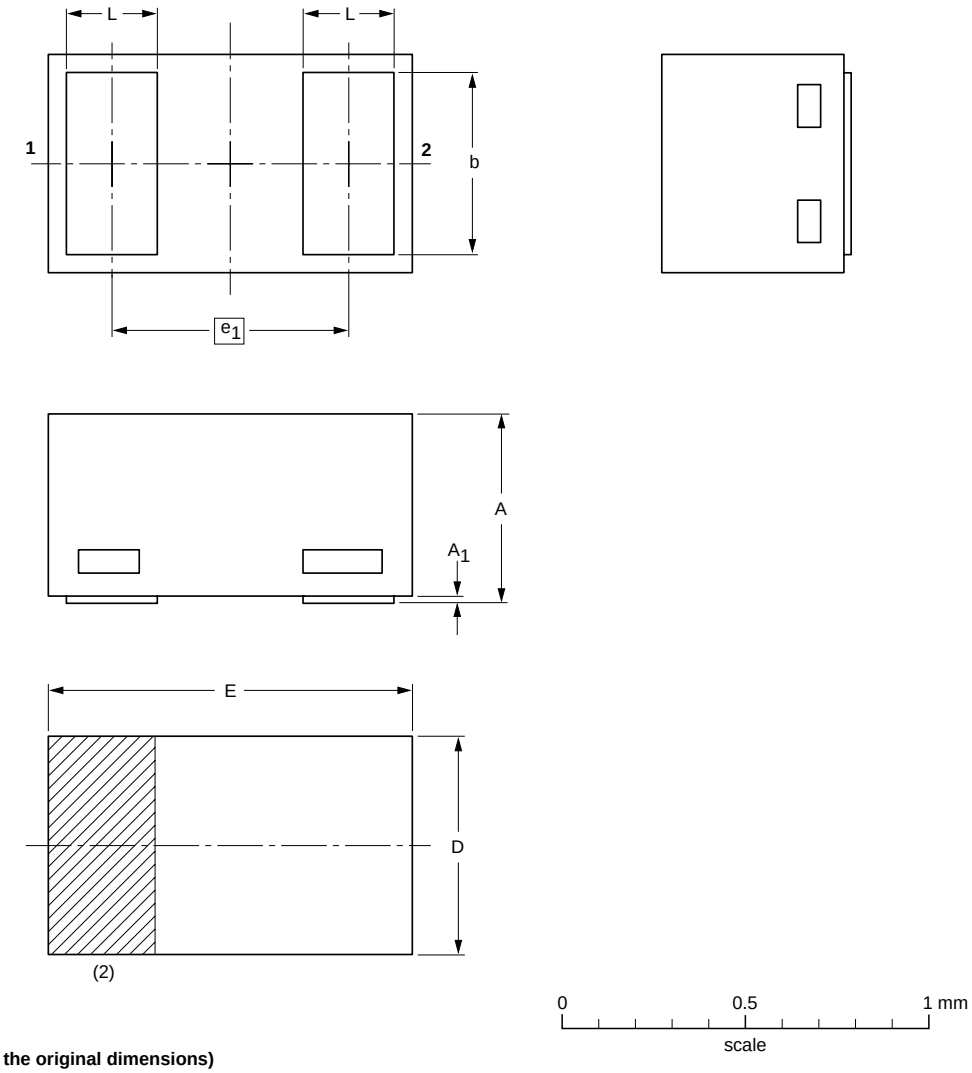
Diode zero biased and inserted in series with a 50 Ω stripline circuit.

T_{amb} = 25 °C.

Fig 4. Isolation ($|s_{12}|^2$) of the diode as a function of frequency; typical values

8. Package outline

Leadless ultra small plastic package; 2 terminals; body 1.0 x 0.6 x 0.5 mm **SOD882**



DIMENSIONS (mm are the original dimensions)

UNIT	A(1)	A_1 max.	b	D	E	e_1	L
mm	0.50 0.46	0.03	0.55 0.47	0.62 0.55	1.02 0.95	0.65	0.30 0.22

Notes

1. Including plating thickness
2. The marking bar indicates the cathode

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOD882						~~03-04-16~~ 03-04-17

Fig 5. Package outline SOD882

9. Revision history

Table 7: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BAP55L_1	20050405	Preliminary data sheet	-	9397 750 14811	-

10. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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